

SN74UVP1G06-Q1 Low-Power Single Inverter With Open-Drain Outputs

1 Features

- AEC-Q100 qualified for automotive applications:
 - Device temperature grade 1: -40°C to +125°C
 - Device HBM ESD classification level 2
 - Device CDM ESD classification level C4B
- Extended low-voltage operation with 0.63V to 3.6V supply range
- Extended operating temperature range: -40°C to 125°C
- Low power consumption
 - Typical $I_{CC} = 10\text{nA}$
 - Typical input leakage $I_I = 3\text{nA}$
 - Typical output off-state leakage current $I_{OZ} = 100\text{nA}$
 - Typical partial-power-down $I_{OFF} = 0.2\mu\text{A}$
- 3.6V tolerant input to support down translation
- Maximum t_{pd} of 9.5ns at 3.3V
- Drop-in compatible with AUP1G family and V_{CC} extended from 0.8V to 0.63V

2 Applications

- [Advanced driver assistance systems \(ADAS\)](#)
- [Body electronics and lighting](#)
- [Infotainment and cluster](#)

3 Description

The SN74UVP1G06-Q1 device is a low-power single inverter with open drain output, and performs the Boolean function $Y = \bar{A}$.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
SN74UVP1G06-Q1	DBV (SOT-23, 5)	2.90mm × 1.60mm
SN74UVP1G06-Q1	DCK (SC-70, 5)	2.00mm × 1.25mm
	DTX (X2SON, 5)	1.10mm × 0.85mm
	DRY (USON, 6)	1.45mm × 1.00mm

(1) For more information, see [Section 11](#).

(2) The body size (length × width) is a nominal value and does not include pins



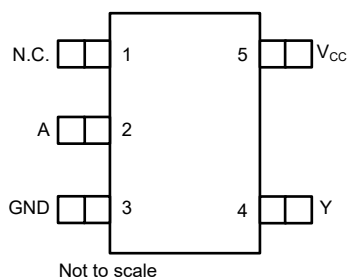
Logic Diagram



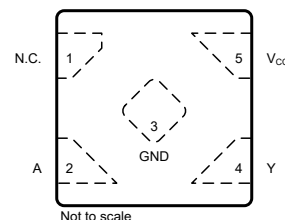
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4 Pin Configuration and Functions



**Figure 4-1. DBV or DCK Package,
5-Pin SOT-23 or SC-70
(Top View)**

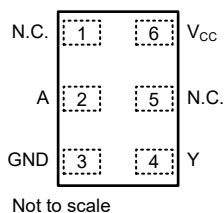


**Figure 4-2. or DTX Package,
5-Pin X2SON
(Top View)**

Table 4-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	DBV, DCK, DTX		
N.C.	1	—	Not internally connected
A	2	I	Input A
GND	3	G	Ground pin
Y	4	O	Output Y (push pull)
VCC	5	P	Power pin

(1) I = Input, O = Output, G = Ground, P = Power



**Figure 4-3. DRY Package,
5-Pin USON or X2SON
(Top View)**

Table 4-2. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	DRY		
N.C.	1, 5	—	Not internally connected
A	2	I	Input A
GND	3	G	Ground pin
Y	4	O	Output Y (push pull)
VCC	6	P	Power pin

(1) I = Input, O = Output, G = Ground, P = Power

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6	V
V _I	Input voltage range ⁽²⁾		-0.5	6	V
V _O	Output voltage range ⁽²⁾		-0.5	V _{CC} + 0.5	V
V _O	Output voltage range ⁽²⁾		-0.5	6	V
I _{IK}	Input clamp current	V _I < 0V		-50	mA
I _{OK}	Output clamp current	V _O < 0V		-50	mA
I _O	Continuous output current			±50	mA
I _O	Continuous output current through V _{CC} or GND			±100	mA
T _J	Junction temperature		-65	150	°C
T _{stg}	Storage temperature		-65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 HBM ESD Classification Level 2 ⁽¹⁾	±2000	V
		Charged device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B	±1000	

- (1) AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

Specifications	Description	Condition	MIN	MAX	UNIT
V _{CC}	Supply voltage		0.63	3.6	V
V _I	Input voltage		0	5.5	V
V _O	Output voltage		0	5.5	V
V _{IH}	High-level input voltage	V _{CC} = 0.63V to 0.77V	0.65 × V _{CC}		V
		V _{CC} = 0.72V to 0.88V	0.65 × V _{CC}		
		V _{CC} = 0.9V to 1.1V	0.65 × V _{CC}		
		V _{CC} = 1.08V to 1.32V	0.65 × V _{CC}		
		V _{CC} = 1.35V to 1.65V	0.65 × V _{CC}		
		V _{CC} = 1.62V to 1.98V	0.65 × V _{CC}		
		V _{CC} = 2.3V to 2.7V	1.7		
		V _{CC} = 3.0V to 3.6V	2		

5.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)

Specifications	Description	Condition	MIN	MAX	UNIT
V _{IL}	Low-Level input voltage	V _{CC} = 0.63V to 0.77V		0.35 × V _{CC}	V
		V _{CC} = 0.72V to 0.88V		0.35 × V _{CC}	
		V _{CC} = 0.9V to 1.1V		0.35 × V _{CC}	
		V _{CC} = 1.08V to 1.32V		0.35 × V _{CC}	
		V _{CC} = 1.35V to 1.65V		0.35 × V _{CC}	
		V _{CC} = 1.62V to 1.98V		0.35 × V _{CC}	
		V _{CC} = 2.3V to 2.7V		0.7	
		V _{CC} = 3.0V to 3.6V		0.8	
I _{OL}	Low-level output current	V _{CC} = 0.63V		0.2	mA
		V _{CC} = 0.72V		0.5	
		V _{CC} = 0.9V		0.7	
		V _{CC} = 1.08V		1.1	
		V _{CC} = 1.35V		1.7	
		V _{CC} = 1.62V		1.9	
		V _{CC} = 2.3V		3.1	
		V _{CC} = 3.0V		4	
Δt/Δv	Input transition rise or fall rate	V _{CC} = 0.65V to 3.6V		200	ns/V
T _A	Operating free-air temperature		-40	125	°C

5.4 Thermal Information

PACKAGE	PINS	THERMAL METRIC ⁽¹⁾						UNIT
		R _{θJA}	R _{θJC(top)}	R _{θJB}	Ψ _{JT}	Ψ _{JB}	R _{θJC(bot)}	
DBV (SOT-23, 5)	5	298.6	240.2	134.6	114.5	133.9	n/a	°C/W
DCK (SC-70, 5)	5	314.4	128.7	100.6	7.1	99.8	n/a	°C/W
DTX (X2SON, 5)	5							°C/W
DRY (USON, 6)	6	554.9	385.4	388.2	159.0	384.1	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V _{OL}	I _{OL} = 20μA	0.63V to 3.6V			0.15	V
	I _{OL} = 0.7mA	1.0V			0.35	
	I _{OL} = 1.1mA	1.2V			0.25	
	I _{OL} = 1.7mA	1.5V			0.23	
	I _{OL} = 1.9mA	1.65V			0.23	
	I _{OL} = 3.1mA	2.3V			0.26	
	I _{OL} = 3.5mA	2.7V			0.27	
	I _{OL} = 4mA	3V			0.29	
I _I	V _I = V _{CC} or GND	V _{CC} = 0V to 3.6V	±0.003		±0.5	μA
I _{OFF}	V _I or V _O = V _{CC}	V _{CC} = 0V	±0.2		±1	μA
I _{OZ}	V _O = V _{CC} or GND	3.6V	±0.1		±1.5	μA

5.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
I _{CC}	V _I = V _{CC} or GND, I _O = 0	V _{CC} = 0.63V to 3.6V		0.01	1.4	μA
ΔI _{CC}	One input at V _{CC} - 0.6V, other inputs at V _{CC} or GND	3.3V			60	μA
C _I	V _I = V _{CC} or GND	3.3V		4.4		pF
C _O	V _O = V _{CC} or GND	3.3V		2.59		pF

5.6 Switching Characteristics

over operating free-air temperature range; typical values measured at T_A = 25°C (unless otherwise noted). See *Parameter Measurement Information*

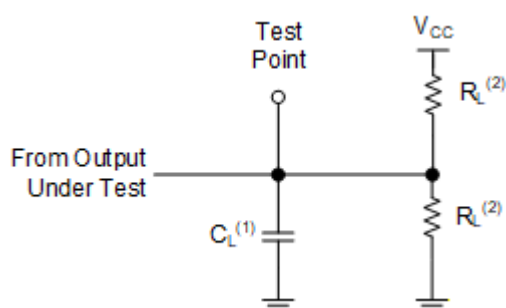
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CONDITION	V _{CC}	MIN	TYP	MAX	UNIT
t _{pd}	A	Y	C _L = 5pF	0.7V ± 0.07V			302	ns
				0.8V ± 0.08V			105.5	ns
			C _L = 10pF	1.0V ± 0.1V			25.1	ns
				1.2V ± 0.12V			16.4	ns
			C _L = 15pF	1.5V ± 0.15V			5.7	ns
				1.8V ± 0.18V			6.1	ns
			C _L = 30pF	2.5V ± 0.2V			7	ns
				3.3V ± 0.3V			10.1	ns
C _{pd}			f = 10MHz	0.7V		0.46		pF
				0.8V		0.47		pF
				1.0V		0.47		pF
				1.2V		0.47		pF
				1.5V		0.49		pF
				1.8V		0.53		pF
				2.5V		0.72		pF
				3.3V		1		pF

6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily for the examples listed in the following table. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1\text{MHz}$, $Z_O = 50\Omega$, $t_f < 3\text{ns}$.

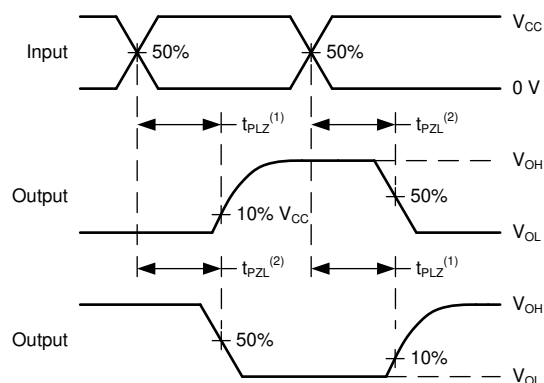
The outputs are measured individually with one input transition per measurement.

TEST	R_L	C_L	ΔV	V_{CC}
t_{pd}	20K Ω	5pF	0.07V	0.7V
			0.08V	0.8V
		10pF	0.1V	1.0V
	5K Ω	10pF	0.12V	1.2V
		15pF	0.15V	1.5V
			0.18V	1.8V
		30pF	0.2V	2.5V
			0.3V	3.3V



- (1) C_L includes probe and test-fixture capacitance.
(2) $R_L = 5\text{k}\Omega$ or $20\text{k}\Omega$ for enable and disable time measurement. $R_L = 1\text{M}\Omega$ for measuring propagation delays, setup and hold times, and pulse width.

Figure 6-1. Load Circuit for Open-Drain Outputs



- (1) If $R_L = 5\text{k}\Omega$, the time between t_{PLZ} and t_{PZL} is the same as disable and enable time.
(2) If $R_L = 1\text{M}\Omega$, t_{PLZ} and t_{PZL} are the same as t_{pd} .

Figure 6-2. Voltage Waveforms Propagation Delays

7 Detailed Description

7.1 Overview

The SN74UVP1G06-Q1 device contains one open-drain inverter with a maximum sink current of 32mA. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

7.2 Functional Block Diagram

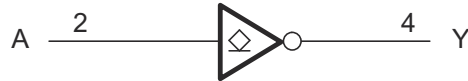


Figure 7-1. Logic Diagram (Positive Logic)

7.3 Feature Description

7.3.1 Open-Drain CMOS Outputs

Open-drain outputs are included in SN74UVP1G06-Q1. Open-drain outputs can only drive the output low. When in the high logical state, outputs are in a high-impedance state, meaning outputs neither source nor sink current (with the exception of minor leakage current as defined in the *Electrical Characteristics* table). In the high-impedance state, the output voltage is not controlled by SN74UVP1G06-Q1 and is dependent on external factors.

Because of the high-impedance state, an external pull-up resistor is required to define a logic high. Without a pull-up resistor, the output will float and have an undefined logic level. The resistor value depends on factors like parasitic capacitance and power consumption; typically, a 10kΩ resistor is suitable.

The drive capability of SN74UVP1G06-Q1 can create fast edges into light loads, so consider routing and load conditions to prevent ringing. Additionally, outputs can drive higher currents than SN74UVP1G06-Q1 is designed to handle continuously. Limit the device output power to avoid damage due to overcurrent. Follow the electrical and thermal limits defined in the *Absolute Maximum Ratings* at all times. See the *Recommended Operating Conditions* table for the maximum output voltage that can be externally connected to SN74UVP1G06-Q1.

Leave unused open-drain CMOS outputs disconnected.

7.3.2 Standard CMOS Inputs

This device includes standard CMOS inputs. Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law ($R = V \div I$).

Standard CMOS inputs require that input signals transition between valid logic states quickly, as defined by the input transition time or rate in the *Recommended Operating Conditions* table. Failing to meet this specification results in excessive power consumption and can cause oscillations. See more details in *Implications of Slow or Floating CMOS Inputs*.

Do not leave standard CMOS inputs floating at any time during operation. Terminate unused inputs at V_{CC} or GND. If a system does not always drive an input, consider adding a pull-up or pull-down resistor to provide a valid input voltage. The resistor value depends on multiple factors; a 10kΩ resistor, however, is recommended and typically meets all requirements.

7.4 Device Functional Modes

[Function Table](#) lists the functional modes of the SN74UVP1G06-Q1.

Table 7-1. Function Table

INPUT A	OUTPUT Y
L	Hi-Z

**Table 7-1. Function Table
(continued)**

INPUT A	OUTPUT Y
H	L

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The SN74UVP1G06-Q1 is a high-drive CMOS device that can be used in an LED application. The device can sink 32mA of current at 4.5V making it appropriate for high-drive applications. The device is good for high-speed applications up to 100MHz. The inputs are 5.5V tolerant allowing it to translate up or down to V_{CC} . [Figure 8-1](#) shows a simple LED driver application for a single channel of the device.

8.2 Typical Application

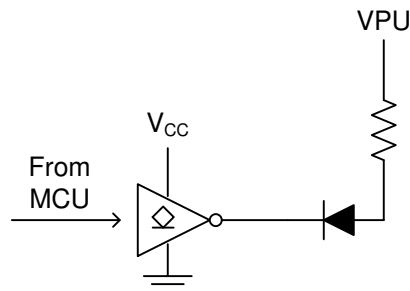


Figure 8-1. Typical Application Diagram

8.3 Design Requirements

8.3.1 Power Considerations

Verify that the desired supply voltage is within the range specified in the *Electrical Characteristics*. The supply voltage sets the device electrical characteristics, as described in the *Electrical Characteristics* section.

The positive voltage supply must be capable of sourcing current equal to the maximum static supply current, I_{CC} , listed in the *Electrical Characteristics*, and any transient current required for switching.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74UVP1G06-Q1 plus the maximum supply current, I_{CC} , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current that can be sunk into the ground connection. Verify that the maximum total current through GND listed in the *Absolute Maximum Ratings* is not exceeded.

The SN74UVP1G06-Q1 can drive a load with a total capacitance less than or equal to 30 pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, TI recommends adding a series resistor between the output and capacitor to prevent excessive current.

The SN74UVP1G06-Q1 can drive a load with total resistance described by $R_L \geq V_O / I_O$, with the output voltage and current defined in the *Electrical Characteristics* table with V_{OL} . When outputting in the HIGH state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the V_{CC} pin.

Total power consumption can be calculated using the information provided in the [CMOS Power Consumption and Cpd Calculation application note](#).

Thermal increase can be calculated using the information provided in the [Thermal Characteristics of Standard Linear and Logic \(SLL\) Packages and Devices application note](#).

CAUTION

The maximum junction temperature, $T_{J(max)}$ listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

8.3.2 Input Considerations

Input signals must cross $V_{IL(max)}$ to be considered a logic LOW, and $V_{IH(min)}$ to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either V_{CC} or ground. The unused inputs can be directly terminated if the input is completely unused, or the inputs can be connected with a pullup or pulldown resistor if the input is used sometimes, but not always. A pullup resistor is used for a default state of HIGH, and a pulldown resistor is used for a default state of LOW. The drive current of the controller, leakage current into the SN74UVP1G06-Q1 (as specified in the *Electrical Characteristics*), and the desired input transition rate limits the resistor size. A 10k Ω resistor value is often used due to these factors.

The SN74UVP1G06-Q1 has CMOS inputs and thus requires fast input transitions to operate correctly, as defined in the Electrical Characteristics table. Slow input transitions can cause oscillations, additional power consumption, and reduction in device reliability.

Refer to the *Feature Description* for additional information regarding the inputs for this device.

8.3.3 Output Considerations

The ground voltage is used to produce the output LOW voltage. Sinking current into the output increases the output voltage as specified by the V_{OL} specification in the *Electrical Characteristics*.

Open-drain outputs can be connected together directly to produce a wired-AND configuration or for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to V_{CC} or ground.

Refer to the *Feature Description* section for additional information regarding the outputs for this device.

8.3.4 Detailed Design Procedure

1. Add a decoupling capacitor from V_{CC} to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V_{CC} and GND pins. An example layout is shown in the *Layout* section.
2. Verify that the capacitive load at the output is $\leq 50\text{pF}$. Low load capacitance can be accomplished by providing short, appropriately sized traces from the SN74UVP1G06-Q1 to the receiving device.
3. Verify that the resistive load at the output is larger than $(V_{CC} / I_{O(max)})\Omega$. Never violate the maximum output current from the *Absolute Maximum Ratings*. Most CMOS inputs have a resistive load measured in M Ω ; much larger than the minimum calculated previously.
4. Thermal issues are rarely a concern for logic gates; however, the power consumption and thermal increase can be calculated using the steps provided in the [CMOS Power Consumption and Cpd Calculation application note](#).

8.4 Application Curves

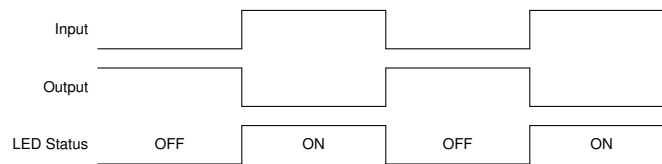


Figure 8-2. Application Curve

8.5 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal must have a good bypass capacitor to prevent power disturbance.

A 0.1 μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1 μ F and 1 μ F capacitors are commonly used in parallel. The bypass capacitor must be installed as close to the power terminal as possible for best results.

8.6 Layout

8.6.1 Layout Guidelines

- Bypass capacitor placement
 - Place near the positive supply terminal of the device
 - Provide an electrically short ground return path
 - Use wide traces to minimize impedance
 - Keep the device, capacitors, and traces on the same side of the board whenever possible
- Signal trace geometry
 - 8mil to 12mil trace width
 - Lengths less than 12cm to minimize transmission line effects
 - Avoid 90° corners for signal traces
 - Use an unbroken ground plane below signal traces
 - Flood fill areas around signal traces with ground
 - Parallel traces must be separated by at least 3x dielectric thickness
 - For traces longer than 12cm
 - Use impedance controlled traces
 - Source-terminate using a series damping resistor near the output
 - Avoid branches; buffer each signal that must branch separately

8.6.2 Layout Example

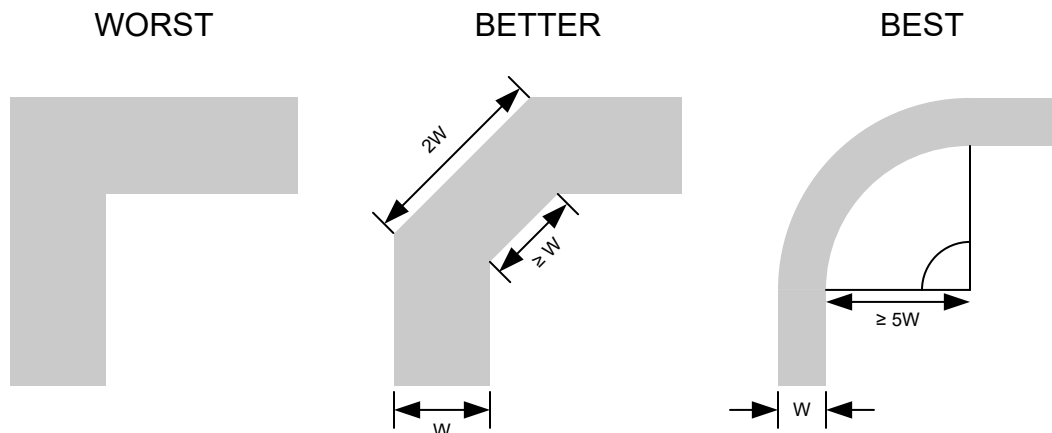


Figure 8-3. Example Trace Corners for Improved Signal Integrity

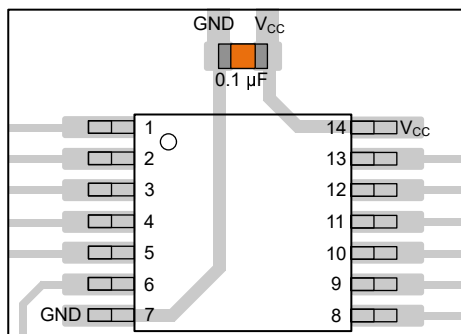


Figure 8-4. Example Bypass Capacitor Placement for TSSOP and Similar Packages

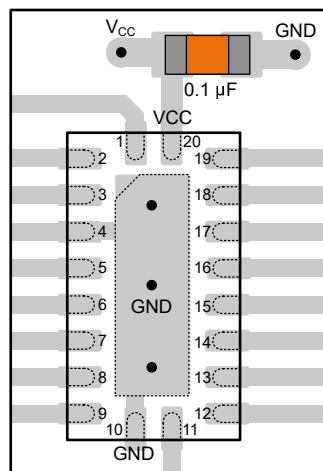


Figure 8-5. Example Bypass Capacitor Placement for WQFN and Similar Packages

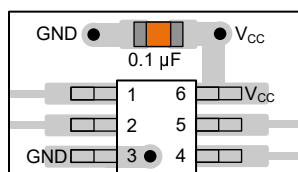


Figure 8-6. Example Bypass Capacitor Placement for SOT, SC70 and Similar Packages

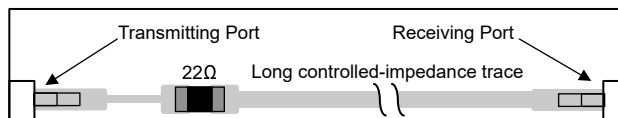


Figure 8-7. Example Damping Resistor Placement for Improved Signal Integrity

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [CMOS Power Consumption and \$C_{pd}\$ Calculation application note](#)
- Texas Instruments, [Designing With Logic application note](#)
- Texas Instruments, [Thermal Characteristics of Standard Linear and Logic \(SLL\) Packages and Devices application note](#)

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

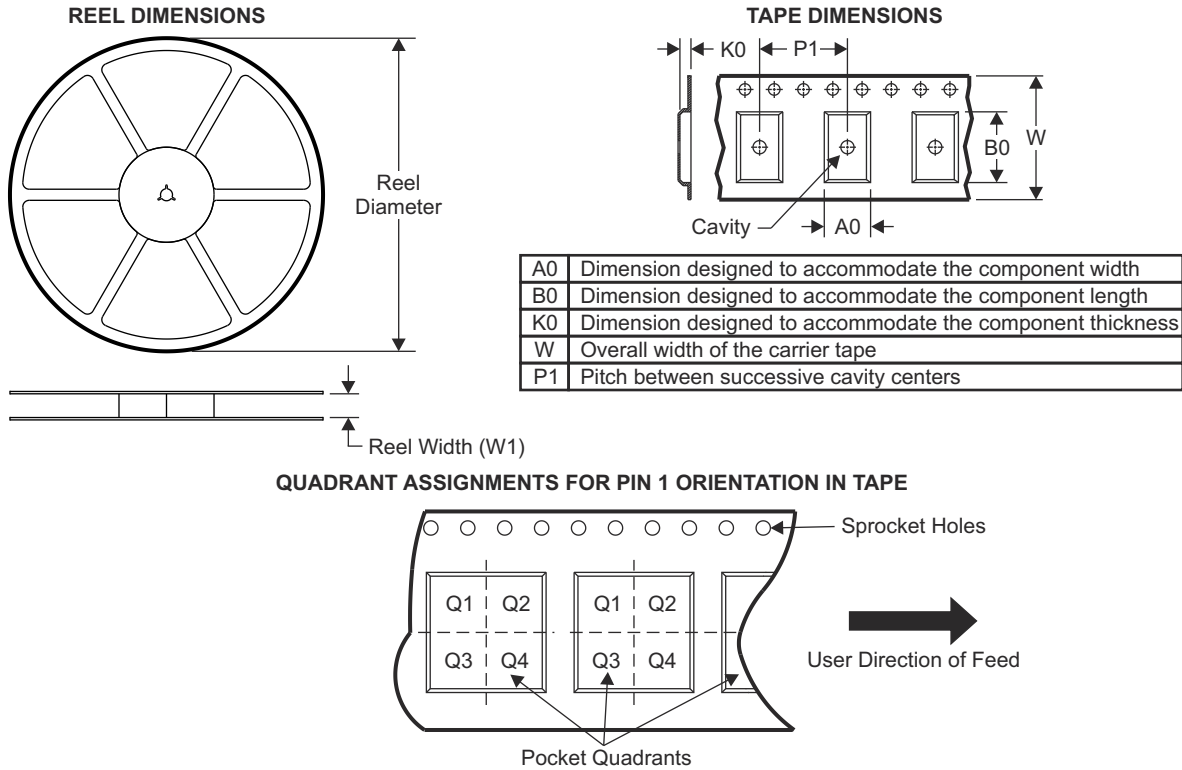
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
August 2026	*	Initial Release

11 Mechanical, Packaging, and Orderable Information

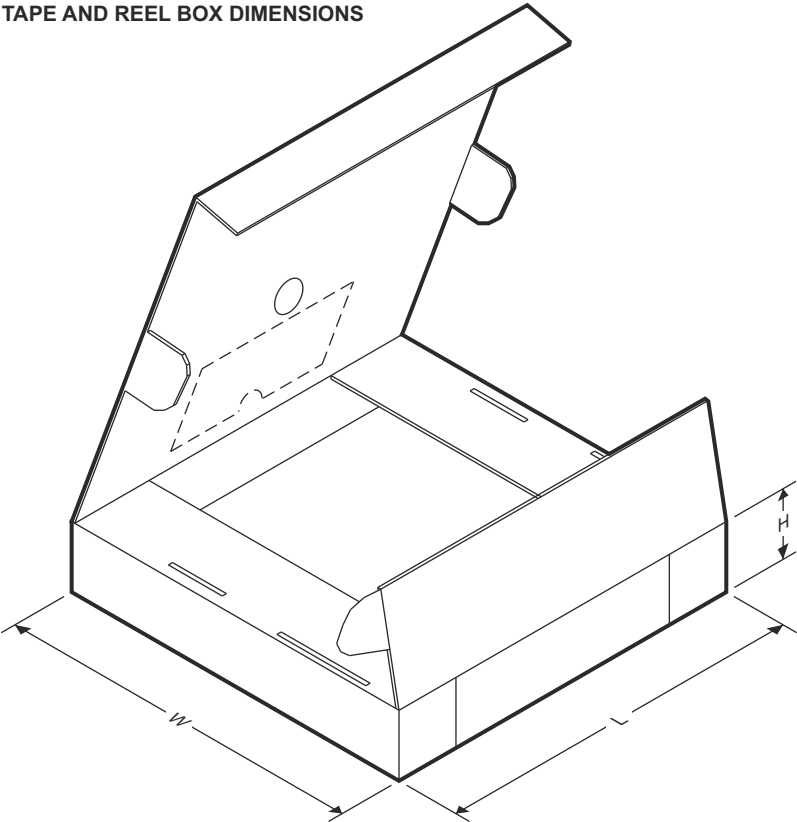
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

11.1 Tape and Reel Information



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
PSN74UVP1G06DBV RQ1	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
PSN74UVP1G06DC KRQ1	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
PSN74UVP1G06DR YRQ1	USON	DRY	5	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
PSN74UVP1G06DTX RQ1	X2SON	DTX	5	3000	180.0	8.4	1.0	1.25	0.48	2.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
PSN74UVP1G06DBVRQ1	SOT-23	DBV	5	3000	208.0	191.0	35.0
PSN74UVP1G06DCKRQ1	SC70	DCK	5	3000	208.0	191.0	35.0
PSN74UVP1G06DRYRQ1	USON	DRY	5	5000	184.0	184.0	19.0
PSN74UVP1G06DTXRQ1	X2SON	DTX	5	3000	210.0	185.0	35.0

11.2 Mechanical Data

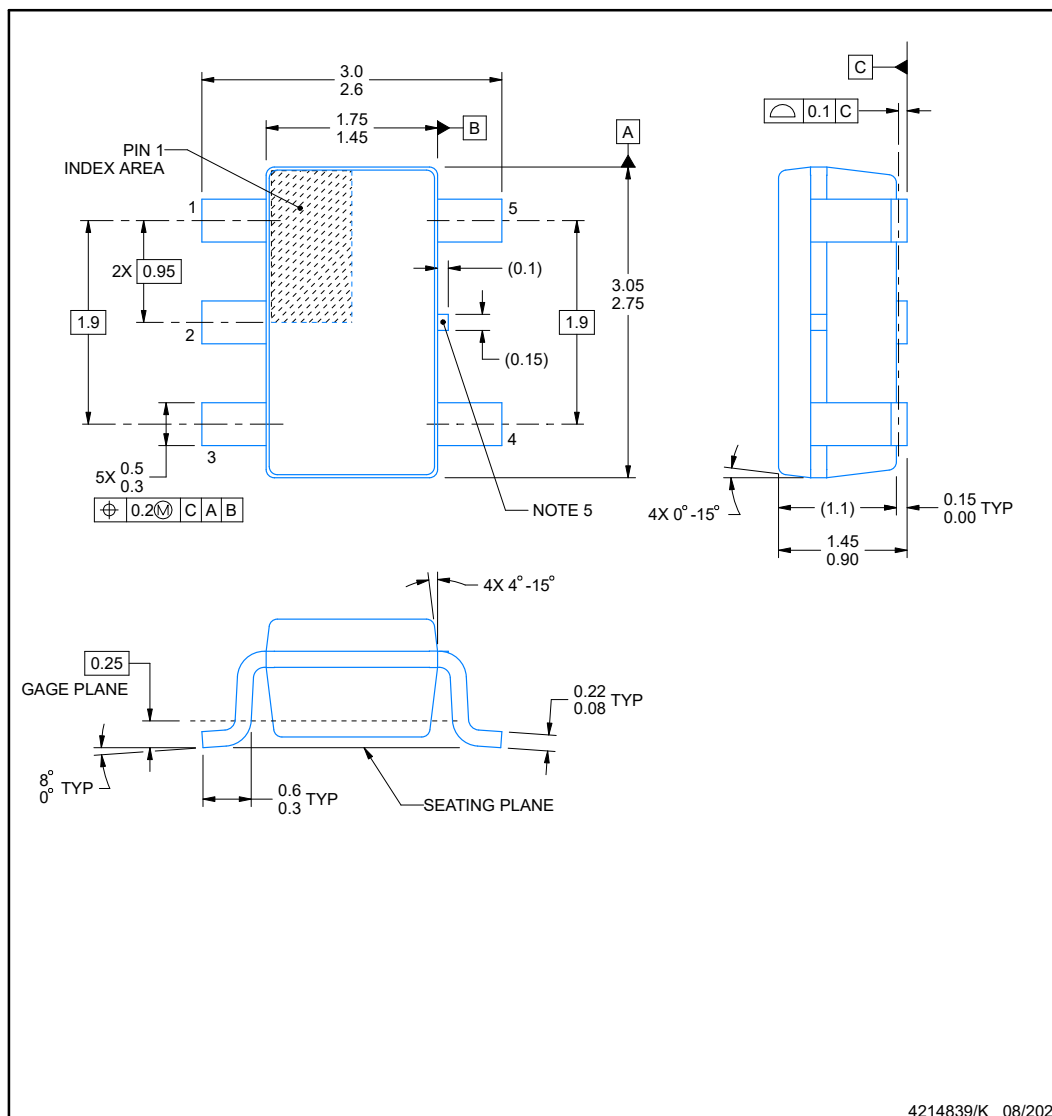
DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

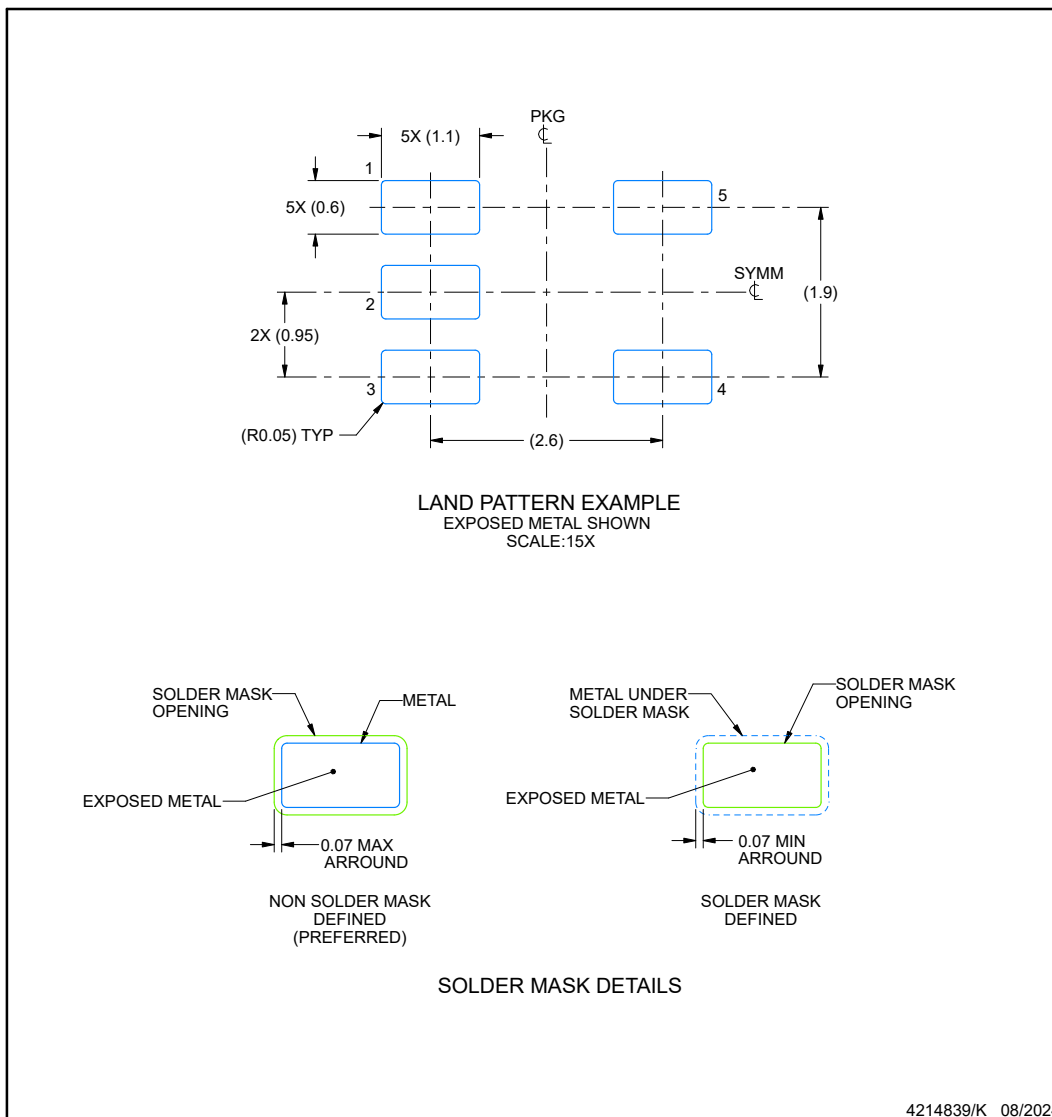
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

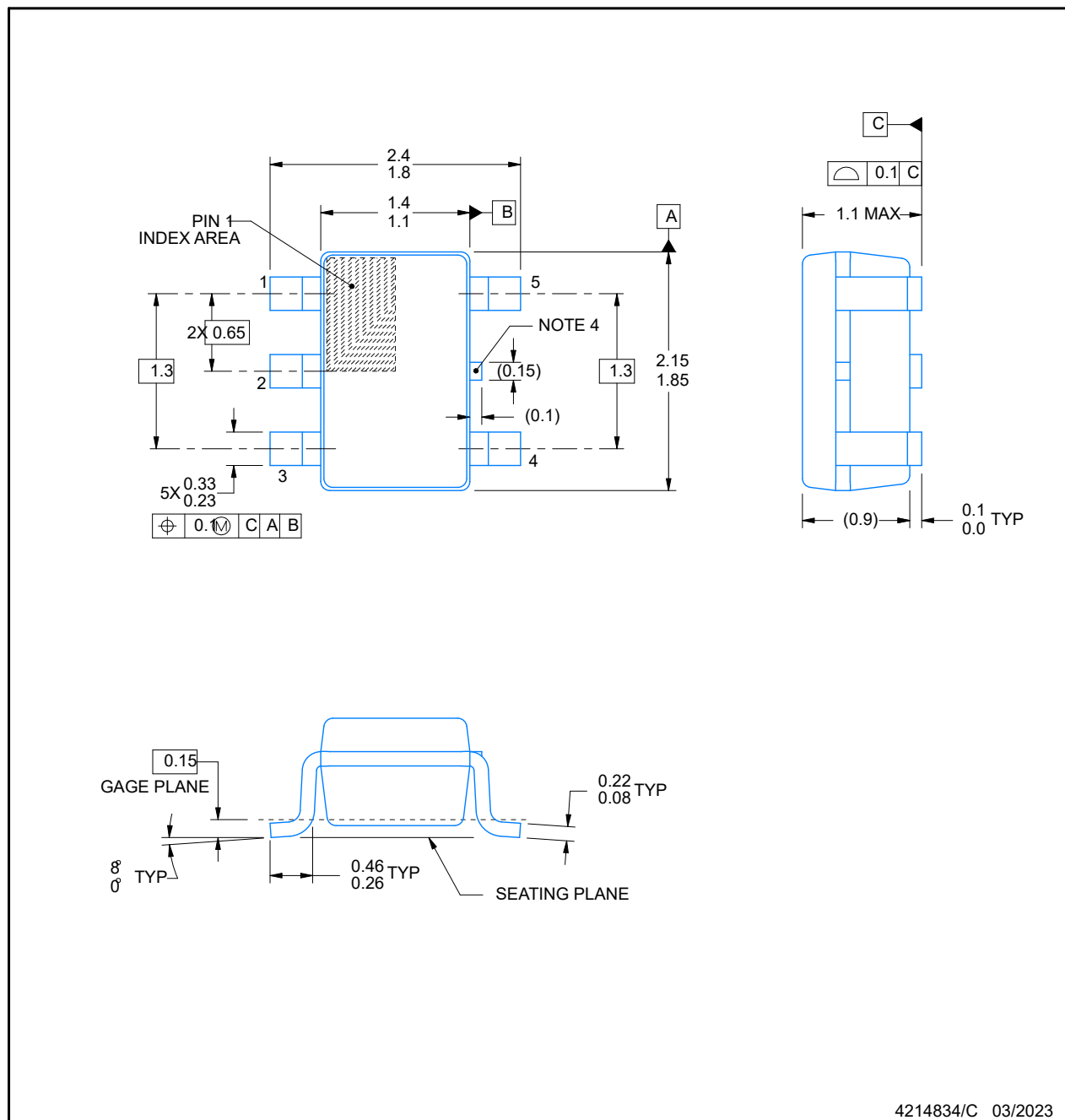


DCK0005A

PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



ADVANCE INFORMATION

NOTES:

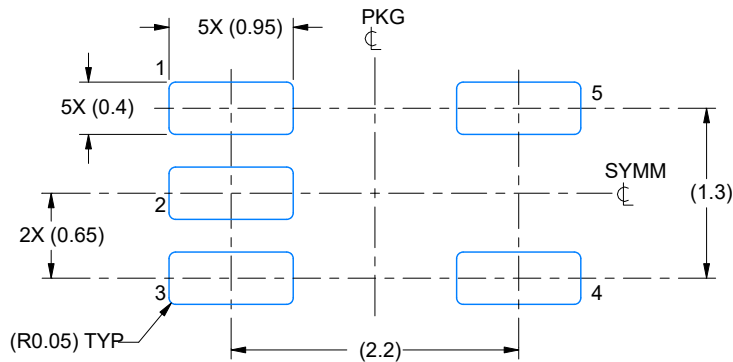
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

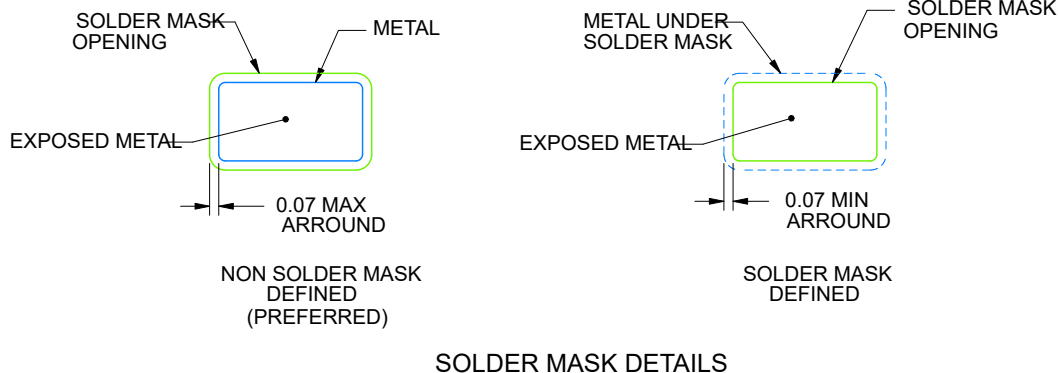
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X



4214834/C 03/2023

NOTES: (continued)

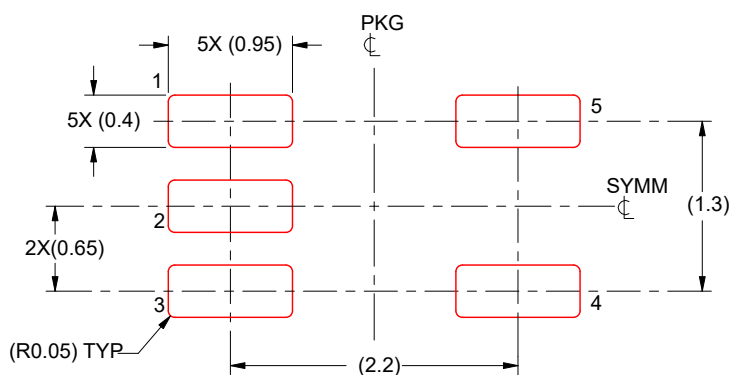
4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/C 03/2023

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

ADVANCE INFORMATION

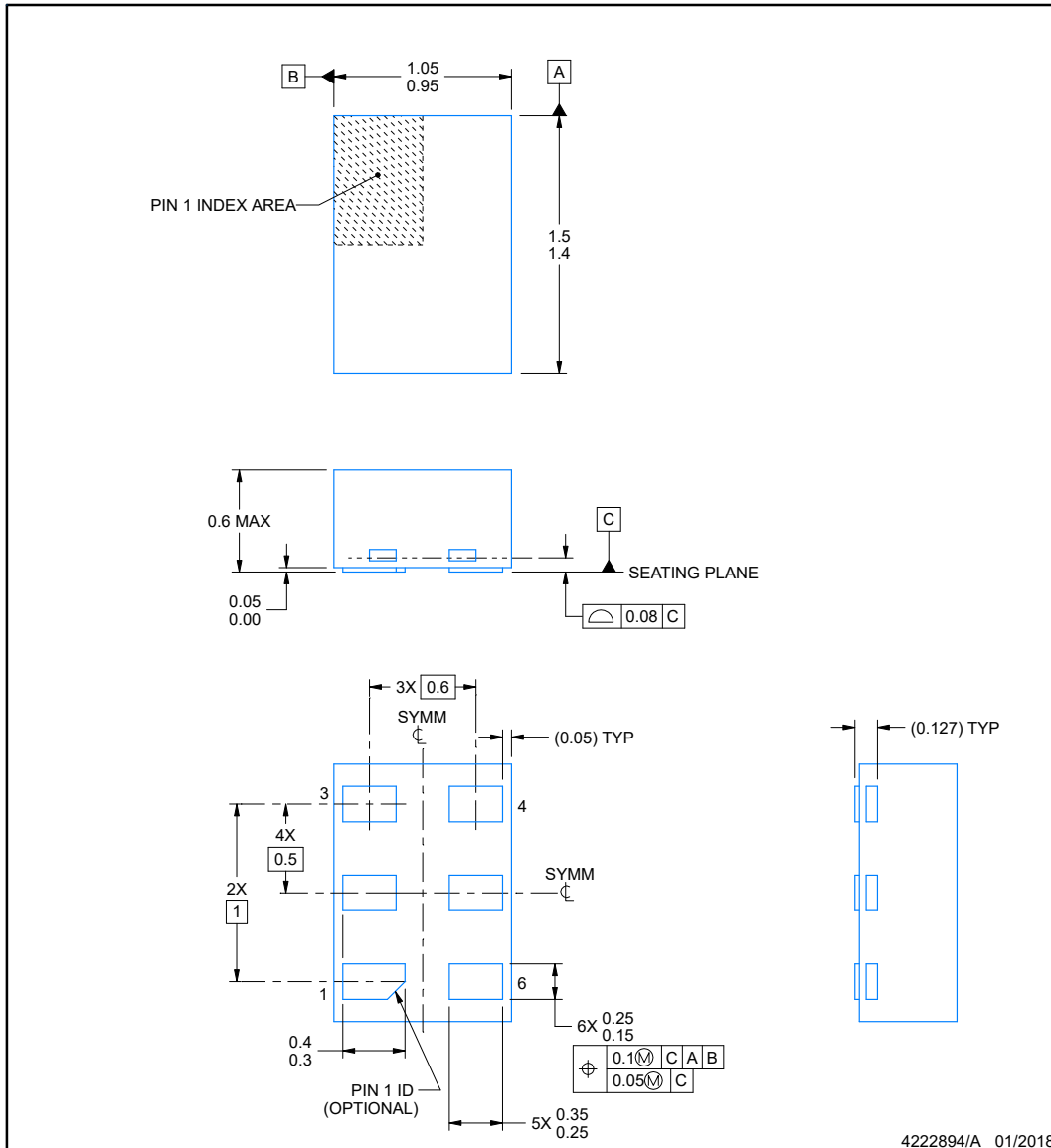
DRY0006A



PACKAGE OUTLINE

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

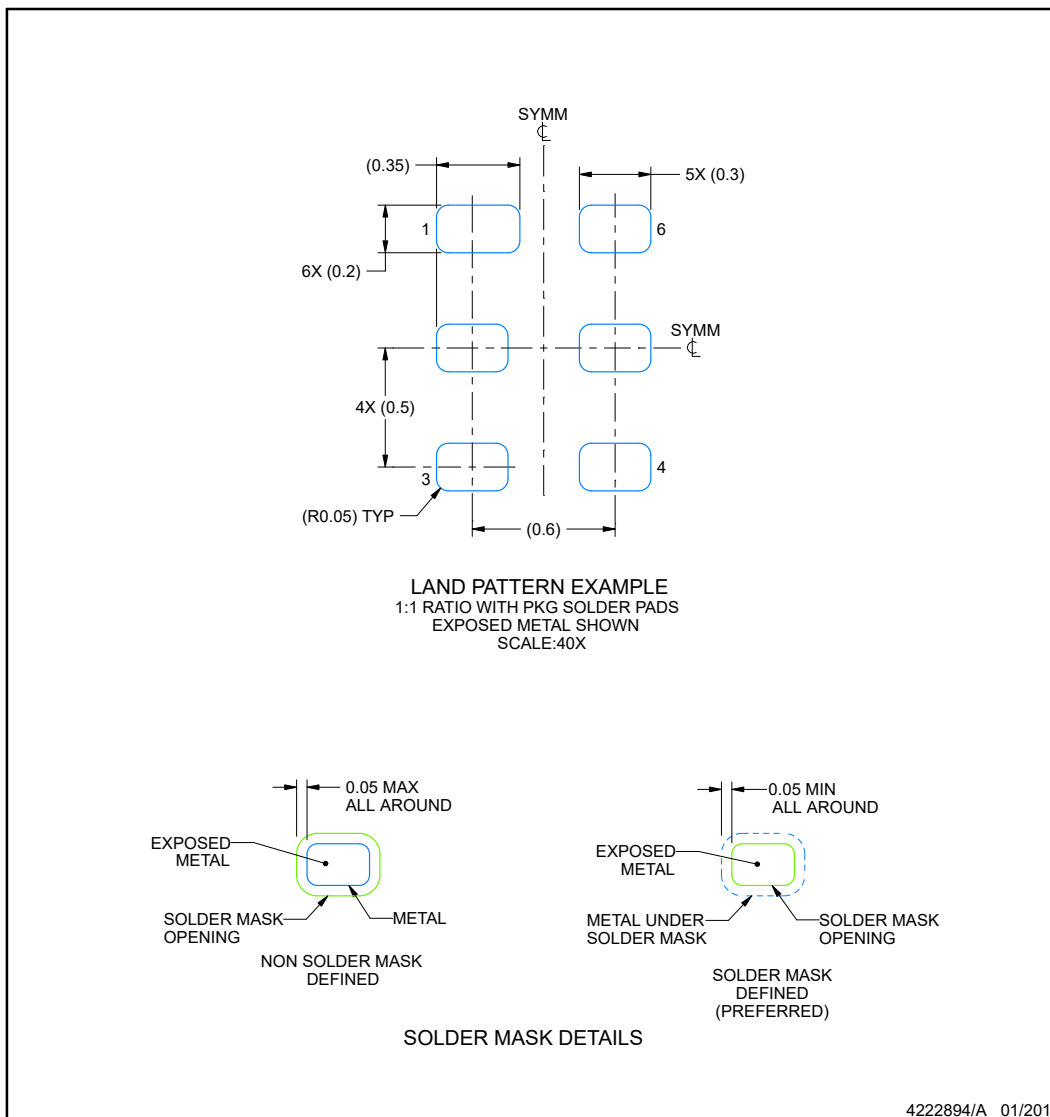
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

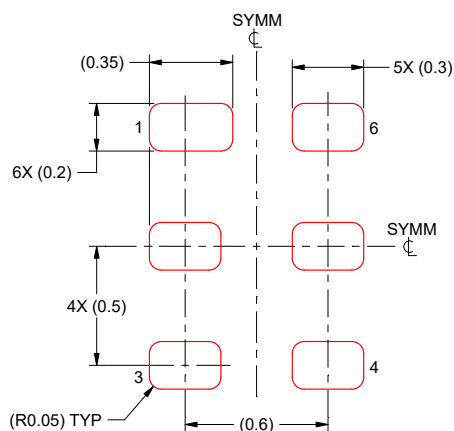
3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/sluea271).

EXAMPLE STENCIL DESIGN

DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1 mm THICK STENCIL
SCALE:40X

4222894/A 01/2018

NOTES: (continued)

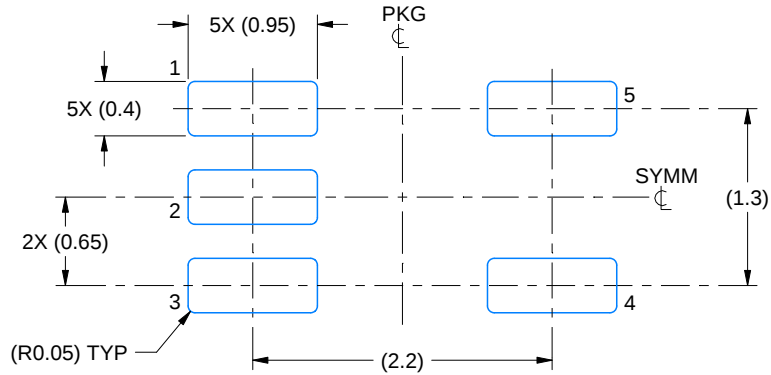
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

EXAMPLE BOARD LAYOUT

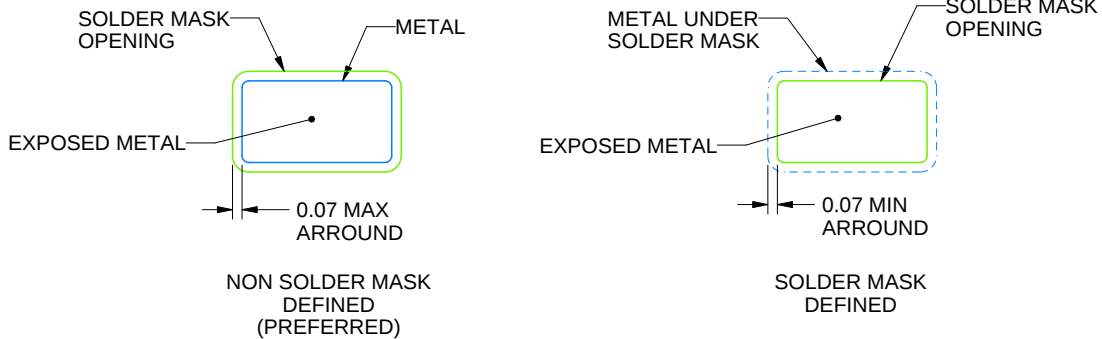
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

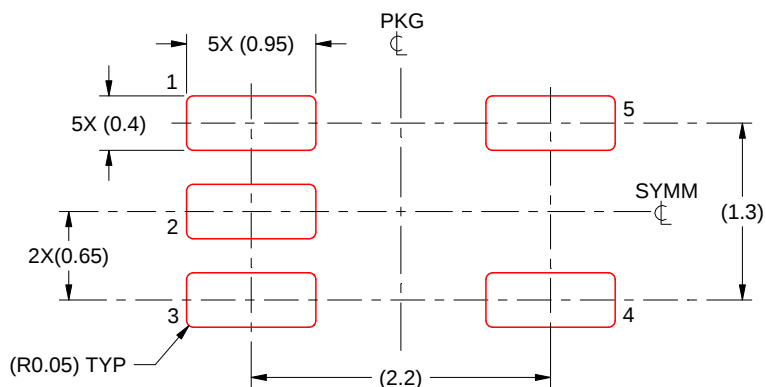


SOLDER MASK DETAILS

4214834/G 11/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/G 11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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Last updated 10/2025